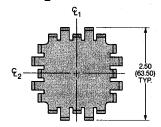
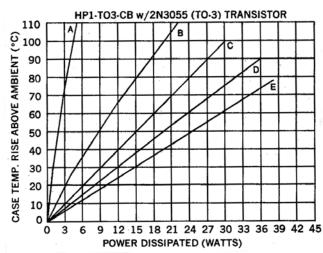


Technical Data

METAL CASE, CASE-MOUNTED SEMICONDUCTORS

HP1 Series for Single TO-3 or Stud Mount Devices







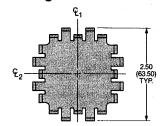
DESCRIPTION OF CURVES

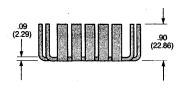
- A. N.C. Horiz. Device Only Mounted to G-10.
- A. N.C. Horiz. & Vert. With Dissipator.
- B. 200 RPM w/Diss.
- C. 500 RPM w/Diss.
- E. 1000 RPM w/Diss.

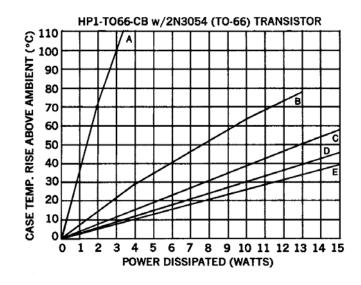
- Thermal Resistance Case to Sink is 0.1-0.3 °C/W w/Joint Compound.
- Derate 1.0 °C/watt for unplated part in natural convection only.

IERC PART NO.			Semiconductor	Hole patt.	Max. Weight
Unplated	Comm'l. Black Anodize	Mil. Black Anodize	Accommodated	Ref. No. (see pg. 1-28)	(Grams)
HP1-000-U	HP1-000-CB	HP1-000-B	Undrilled		35.0
HP1-TO3-U	HP1-TO3-CB	HP1-TO3-B	TO-3	16	35.0
HP1-TO3-33U	HP1-TO3-33CB	HP1-TO3-33B	TO-3 IC	17	35.0
HP1-TO3-44U	HP1-TO3-44CB	HP1-TO3-44B	TO-3 panel mount	31	35.0
HP1-436-U	HP1-436-CB	HP1-436-B	TO-3 (4-pin)	18	35.0
HP1-TO6-U	HP1-T06-CB	HP1-T06-B	TO-6, TO-36	19	35.0
HP1-TO15-U	HP1-TO15-CB	HP1-TO15-B	TO-15, DO-5	23	35.0
HP1-420-U	HP1-420-CB	HP1-420-B	Universal	27	35.0

HP1 Series for Single TO-66 Outline







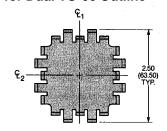
DESCRIPTION OF CURVES

- B. N.C. Horiz. Device Only Mounted to G-10.
- D. N.C. Horiz. & Vert. With Dissipator.
- E. 200 RPM w/Diss.
- F. 500 RPM w/Diss.
- E. 1000 RPM w/Diss.

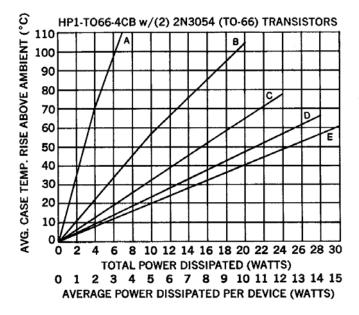
- Thermal Resistance Case to Sink is 0.5-0.7 °C/W w/Joint Compound.
- Derate 1.0 °C/watt for unplated part in natural convection only.

or doring into intended						
IERC PART NO.			Semiconductor	Hole patt.	Max. Weight	
Unplated	Comm'l. Black	Mil. Black	Accommodated	Ref. No.	(Grams)	
	Anodize	Anodize		(see pg.		
				1-28)		
HP1-TO66-U	HP1-TO66-CB	HP1-TO66-B	TO-66	24	35.0	
HP1-TO66-35U	HP1-TO66-35CB	HP1-TO66-35B	TO-66 IC	25	35.0	
HP1-TO66-49U	HP1-TO66-49CB	HP1-TO66-49B	TO-66 IC (Socket)	26	35.0	

HP1 Series for Dual TO-66 Outline







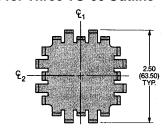
DESCRIPTION OF CURVES

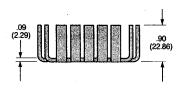
- C. N.C. Horiz. Device Only Mounted to G-10.
- G. N.C. Horiz. & Vert. With Dissipator.
- H. 200 RPM w/Diss.
- I. 500 RPM w/Diss.
- E. 1000 RPM w/Diss.

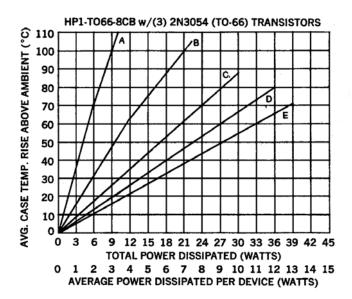
- Thermal Resistance Case to Sink is 0.5-0.7 °C/W w/Joint Compound.
- Derate 2.0 °C/watt per device for unplated part in natural convection only.
- Case Temperatures Match Within 2°C at equivalent power levels.

IERC PART NO.			Semiconductor	Hole patt.	Max. Weight		
Unplated	Comm'l. Black Anodize	Mil. Black Anodize	Accommodated	Ref. No. (see pg. 1-30)	(Grams)		
HP1-TO66-4U HP1-TO66-36U	HP1-TO66-4CB HP1-TO66-36CB	HP1-TO66-4B HP1-TO66-36B	Two TO-66s Two TO-66 Ics	32 34	35.0 35.0		

HP1 Series for Three TO-66 Outline







DESCRIPTION OF CURVES

- D. N.C. Horiz. Device Only Mounted to G-10.
- N.C. Horiz. & Vert. With Dissipator.
- K. 200 RPM w/Diss.
- L. 500 RPM w/Diss.
- E. 1000 RPM w/Diss.

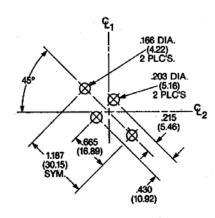
- Thermal Resistance Case to Sink is 0.5-0.7 °C/W w/Joint Compound.
- Derate 3.0 °C/watt per device for unplated part in natural convection only.
- Case Temperatures Match Within 2°C at equivalent power levels in natural convection.

IERC PART NO.			Semiconductor	Hole patt.	Max. Weight
Unplated	Comm'l. Black	Mil. Black	Accommodated	Ref. No.	(Grams)
	Anodize	Anodize		(see pg. 1-30)	
HP1-TO66-8U	HP1-TO66-8CB	HP1-TO66-8B	Two TO-66s	33	35.0
HP1-TO66-39U	HP1-TO66-39CB	HP1-TO66-39B	Two TO-66 Ics	35	35.0

HOLE PATTERNS

16. Hole pattern no. 1 accommodates T0-3s. Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.

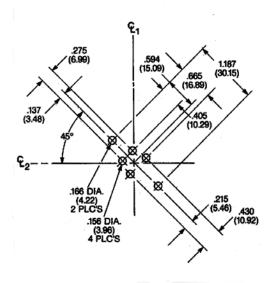
17. Hole pattern no. 202 accommodates T0-3 ICs. Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.

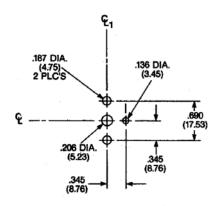


(3.86) 2 PLC'S (2.43) ON .500 DIA. B.C. 45° 7 PLC'S TYP. 40° 7 PLC'S 1.187 (30.15)

18. Hole pattern no. 436 accommodates t0-3s (4-pin). Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.

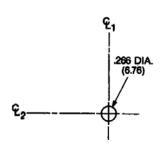
19. Hole pattern no. 2 accommodates T0-6s or T0-36s. Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.





23. Hole pattern no. 3 accommodates TO-15s, DO-5s and other $\frac{1}{2}$ " stud mount devices. Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.

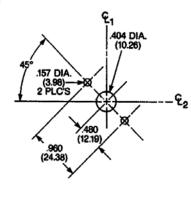
24. Hole pattern no. 114 accommodates TO-66s. Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.

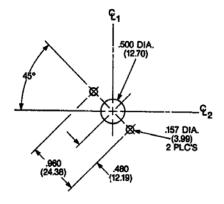


157 DIA. (3.99) 2 PLC'S .078 DIA. (1.98) 2 PLC'S 2 PLC'S (1.4.73) 2 PLC'S (5.08) (24.38) 3 (5.08)

25. Hole pattern no. 199 accommodates TO-66 ICs. Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.

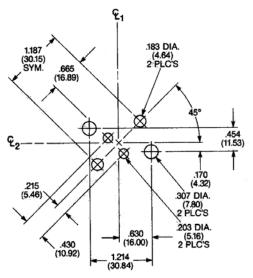
26. Hole pattern no. 226 accommodates TO-66 ICs (socket). Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.

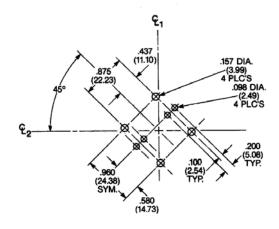




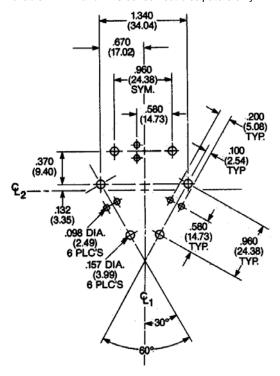
31. Hole pattern no. 213 accommodates one TO-3 (panel mounted). Available in HP1 and HP3 series heat dissipators only.

32. Hole pattern no. 150 accommodates two TO-66s. Available in HP1 and HP3 series heat dissipators only.

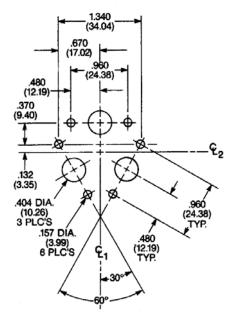




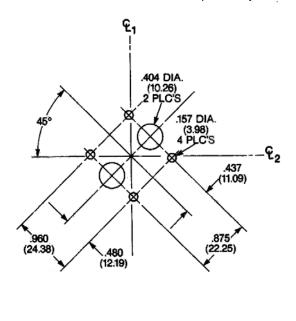
33. Hole pattern no. 185 accommodates three TO-66s. Available in HP1 and HP3 series heat dissipators only.



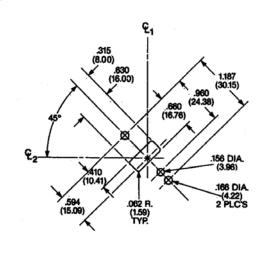
35. Hole pattern no. 203 accommodates three TO-66 ICs. Available in HP1 and HP3 series heat dissipators only.



34. Hole pattern no. 201 accommodates two TO-66s ICs. Available in HP1 and HP3 series heat dissipators only.



27. Hole pattern no. 420 (Universal) accommodates T0-3s, T0-66s, T0-126s, T0-127s, or T0-220s. Available in UP, UP1, UP2, HP1, and HP3 series heat dissipators.



CTS IERC, Heat Sinks and Thermal Management Solutions

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